

Radiation	Type	Technology	Case
Infrared	DH	AlGaAs/GaAs	5 mm plastic lens

		Description
		High-power, high-speed infrared LED in standard 5 mm package, wide beam angle, housing without standoff leads Note: Special packages with standoff available on request
Applications		Optical communications, safety equipment, automation, optical sensors

Maximum Ratings

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test conditions	Symbol	Value	Unit
Forward current (DC)		I_F	100	mA
Peak forward current	($t_P \leq 50 \mu\text{s}$, $t_P/T = 1/2$)	I_{FM}	200	mA
Power dissipation		P_D	150	mW
Operating temperature range		T_{amb}	-40 to +100	°C
Storage temperature range		T_{stg}	-40 to +100	°C
Junction temperature		T_J	100	°C
Soldering temperature	$t \leq 5 \text{ s}$, 3 mm from case	T_{Sd}	260	°C

Optical and Electrical Characteristics

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test conditions	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 20 \text{ mA}$	V_F		1,17		V
Forward voltage*	$I_F = 100 \text{ mA}$	V_F		1,3	1,5	V
Reverse voltage	$I_R = 100 \mu\text{A}$	V_F	5			V
Radiant power	$I_F = 20 \text{ mA}$	Φ_e	3,8	5,5		mW
Radiant power*	$I_F = 100 \text{ mA}$	Φ_e	20	26		mW
Radiant intensity	$I_F = 20 \text{ mA}$	I_e	7,5	10		mW/sr
Radiant intensity*	$I_F = 100 \text{ mA}$	I_e	30	45		mW/sr
Peak wavelength	$I_F = 50 \text{ mA}$	λ_p	930	950	950	nm
Spectral bandwidth at 50%	$I_F = 50 \text{ mA}$	$\Delta\lambda_{0.5}$		65		nm
Viewing angle	$I_F = 50 \text{ mA}$	φ		45		deg.
Switching time	$I_F = 50 \text{ mA}$	t_r, t_f		35		ns

*measured after 30s current flow

Note: All measurements carried out on EPIGAP equipment

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer.